



AEC-Q100 Qualification Report

Product Series: CA-IF1044AX&1051AX-Q1

Report Version: V1.1

Reference Doc.: AEC-Q100-REV-H&Q006

Prepare	Review	Approve
刘和芳	邵晓梅	陈亮

Contents

1. Overview	3
2. Part Number List	3
3. Production Information.....	3
3.1. Wafer information	3
3.2. Package information	3
4. Reliability Qualification Plan.....	4
5. MTTF&FIT.....	9
6. Conclusion	9

1. Overview

Reliability testing of microelectronic products is a risk mitigation process designed to ensure the service life of device in customer applications. Semiconductor wafer manufacturing process and package-level reliability can be assessed in a variety of ways and may include accelerated environmental test conditions. Chipanalog evaluates manufacturability of the device to verify a robust silicon and assembly flow to ensure continuity of supply to customers. Chipanalog qualifies new devices, significant changes, and product families based on AEC-Q100&AEC-Q006.

2. Part Number List

Package Type	Part Number
SOIC8	CA-IF1044AVS-Q1, CA-IF1044AS-Q1, CA-IF1051AS-Q1, CA-IF1051AVS-Q1
DFN8	CA-IF1044AVD-Q1, CA-IF1044AD-Q1

Note: AECQ-100&AEC-Q006 provides the guideline for the use of generic data to accelerate and streamline the qualification process. Products sharing the same major product, process and materials elements may be categorized in a product qualification family.

3. Production Information

3.1. Wafer information

Fab site	SMIC
Wafer	Blackhole_Q
Fab Process	18BCD

3.2. Package information

Assembly site	UNIMOS	JCET-B	JCET-A
FT site	UNIMOS	JCET-B	JCET-A
Package	SOIC8	DFN8	SOIC8
Lead Frame	Cu	Cu	Cu
Bond wire	25um AuPdCu	20 um AuPdCu	25 um AuPdCu
MSL level	MSL1	MSL1	MSL1
Operation Temp.	Grade 1(-40°C - 125°C)	Grade 1(-40°C - 125°C)	Grade 1(-40°C - 125°C)

4. Reliability Qualification Plan

Test Group A-Accelerated Environment Stress Tests					
Group	Item	Refer.	Test condition	QTY	Remark
A1	PC	J-STD-020 JESD22-A113	Test @ Rm, SMD only, Moisture Preconditioning before THB/BHAST, AC/UHAST, TC, and PTC stress, MSL = 1, Peak Reflow Temp = 260°C	77 pcs*3 lots	
A2	BHAST	JESD22-A110	BHAST: 130°C, 85% RH, V _{cc} = 5.5V, 96,192 hrs (Test @ Rm/Hot)	77 pcs*3 lots	
A3	UHAST	JESD22-A118	UHAST: 130°C, 85% RH, 96 hrs (Test @ Rm)	77 pcs*3 lots	
A4	TC	JESD22-A104	-65°C-150°C, 1000 cycles (Test @Rm/Hot)	77 pcs*3 lots	
A5	PTC	JESD22-A105	-40°C-125°C, 1000 cycles (Test @ Rm/Hot)	NA	
A6	HTSL	JESD22-A103	T _a = 150°C, 2000 hrs (Test @ Rm/Hot)	45 pcs*1 lot	
Test Group B-Accelerated Lifetime Simulation Tests					
Group	Item	Refer.	Test condition	QTY	Remark
B1	HTOL	JESD22-A108	T _a = 125°C, V _{cc} = 5.5V, 1000 hrs (Test @ Rm/Cold/Hot)	77 pcs*3 lots	
B2	ELFR	AEC-Q100-008	T _a = 125°C, V _{cc} = 5.5V, 48 hrs (Test @ Rm/Hot)	800 pcs*3 lots	
B3	EDR	AEC-Q100-005	Test @ Rm/Hot	NA	
Group C-Package Assembly Integrity Tests					
Group	Item	Refer.	Test condition	QTY	Remark
C1	WBS	AEC-Q100-001 AEC-Q003	Cpk > 1.67, T0 samples	30 bonds from 5 pcs	
C1	WBS	AEC-Q100-001 AEC-Q003 AEC-Q006	0 fails, post-TC, UHAST, BHAST, HTS samples	30 bonds from 3 pcs per test item	
C2	WBP	MIL-STD883 AEC-Q003	Cpk > 1.67, T0 samples	30 bonds from 5 pcs	
C2	WBP	MIL-STD883 AEC-Q003 AEC-Q006	0 fails, post-TC, UHAST, BHAST samples	30 bonds from 4 pcs per test item	
C3	SD	J-STD-002	> 95% coverage, 8hr steam aging prior to testing	15 pcs*1 lot	
C4	PD	JESD22-B100 JESD22-B108 AEC-Q003	Cpk > 1.67	10 pcs*3 lots	

C5	SBS	AEC-Q100-010 AEC-Q003	Cpk > 1.67, 5 balls from min. of 10 devices	NA	
C6	LI	JESD22-B105	10 leads from each of 5 devices	NA	
Test Group D–Die Fabrication Reliability Tests					
Group	Item	Refer.	Test condition	QTY	Remark
D1	EM	JESD61	---	---	Done by Fab
D2	TDDDB	JESD35	---	---	Done by Fab
D3	HCI	JESD60 & 28	---	---	Done by Fab
D4	BTI	JESD90	---	---	Done by Fab
D5	SM	JESD61, 87, & 202	---	---	Done by Fab
Group E-Electrical Verification Tests					
Group	Item	Refer.	Test condition	QTY	Remark
E1	TEST	per datasheet	Pre and Post Stress Electrical Test	All	
E2	HBM	AEC Q100-002	±500V, ±1KV, ±2KV, ±4KV, ±8KV (Test @ Rm/Hot)	3 pcs*1 lot	
E3	CDM	AEC-Q100-011	±250V, ±500V, ±750V, ±2KV (Test @ Rm/Hot)	3 pcs*1 lot	
E4	LU	AEC-Q100-004	125℃, I-trigger ±200mA(Test @ Rm/Hot)	3 pcs*1 lot	
E5	ED	AEC-Q100-009	CPK>1.67(Test @ Rm/Cold/Hot)	30 pcs*3 lots	
E9	EMC	SAE J1752/3	Electromagnetic Compatibility (Radiated Emissions)	1 pcs*1 lot	
E10	SC	AEC-Q100-012	/	NA	
E11	SER	JESD89-1/-2/-3	/	NA	
E12	LF	AEC-Q005	/	2 pcs*3 lots	
Group S-Special Requirement Tests					
S1	BLR-Bending	JESD22-B113	Align with customer	NA	
S2	BLR-Drop	JESD22-B11	Align with customer	NA	
S3	BLR-TC	IPC-9701	Refer test requirement	NA	
S4	BLR-Vibration	JESD22-B103	Refer test requirement	NA	

Note: Group E6, E7 and Group F are not reliability related items. Group G are not applicable to non-hermetic packaged devices.

Reliability Test Results

Test Group A-Accelerated Environment Stress Test (SOIC8 JECT-A)					
Group	Item	Test Condition	QTY	Lot NO.	Result
A1	PC	Test @ Rm, SMD only, Moisture Preconditioning before BHAST, UHAST, TC stress, MSL = 1, Peak Reflow Temp = 260℃	240 pcs*3 lots	2513A	Pass
				2514A	Pass
				2515A	Pass
A2	BHAST	130℃, 85% RH, 192 hrs, Vcc= 5.5V	80 pcs*3 lots	2513A	Pass
				2514A	Pass
				2515A	Pass
A3	UHAST	130℃, 85% RH, 96 hrs	80 pcs*3 lots	2513A	Pass
				2514A	Pass
				2515A	Pass
A4	TC	-65℃-150℃, 1000 cycles	80 pcs*3 lots	2513A	Pass
				2514A	Pass
				2515A	Pass
A6	HTSL	Ta = 150℃, 2000 hrs	45 pcs*1 lot	2515A	Pass
Test Group A-Accelerated Environment Stress Test (SOIC8 UNIMOS)					
Group	Item	Test Condition	QTY	Lot NO.	Result
A1	PC	Test @ Rm, SMD only, Moisture Preconditioning before BHAST, UHAST, TC stress, MSL = 1, Peak Reflow Temp = 260℃	240 pcs*3 lots	2513D	Pass
				2514D	Pass
				2515D	Pass
A2	BHAST	130℃, 85% RH, 192 hrs, Vcc= 5.5V	80 pcs*3 lots	2513D	Pass
				2514D	Pass
				2515D	Pass
A3	UHAST	130℃, 85% RH, 96 hrs	80 pcs*3 lots	2513D	Pass
				2514D	Pass
				2515D	Pass
A4	TC	-65℃-150℃, 1000 cycles	80 pcs*3 lots	2513D	Pass
				2514D	Pass
				2515D	Pass
A6	HTSL	Ta = 150℃, 2000 hrs	45 pcs*1 lot	2513D	Pass
Test Group A-Accelerated Environment Stress Test (DFN8 JECT-B)					
Group	Item	Test Condition	QTY	Lot NO.	Result
A1	PC	Test @ Rm, SMD only, Moisture Preconditioning before BHAST, UHAST, TC stress, MSL = 1, Peak Reflow Temp = 260℃	240 pcs*3 lots	2521B	Pass
				2522B	Pass
				2523B	Pass

A2	BHAST	130℃, 85% RH, 192 hrs, V _{cc} = 5.5V	80 pcs*3 lots	2521B	Pass
				2522B	Pass
				2523B	Pass
A3	UHAST	130℃, 85% RH, 96 hrs	80 pcs*3 lots	2521B	Pass
				2522B	Pass
				2523B	Pass
A4	TC	-65℃-150℃, 1000 cycles	80 pcs*3 lots	2521B	Pass
				2522B	Pass
				2523B	Pass
A6	HTSL	T _a = 150℃, 2000 hrs	45 pcs*1 lot	2523B	Pass

Test Group B-Accelerated Lifetime Simulation Tests

Group	Item	Test Condition	QTY	LOT NO.	Result
B1	HTOL	T _a = 125℃, V _{cc} = 5.5V, 1000 hrs (Test @ Rm/Cold/Hot), input f = 1kHz	77 pcs*3 lot	2514A	Pass
				2513D	Pass
				2514D	Pass
B1	HTOL	T _a = 125℃, V _{cc} = 5.5V, 2000 hrs (Test @ Rm/Cold/Hot), input f = 1kHz	77 pcs*2 lot	2513D	Pass
				2514A	Pass
B2	ELFR	T _a = 125℃, V _{cc} = 5.5V, 1000 hrs (Test @ Rm/Cold/Hot), input f = 1kHz	800 pcs*3 lots	2513D	Pass
				2514D	Pass
				2515D	Pass

Group C-Package Assembly Integrity Tests (SOIC8 UNIMOS)

Group	Item	Test Condition	QTY	Lot NO.	Result
C1	WBS	Cpk > 1.67, T0 samples	30 bonds from 5 pcs	2515D	Pass
C1	WBS	0 fails, post-TC, UHAST, BHAST, HTS samples	30 bonds from 3 pcs per test Item	2513D	Pass
				2514D	Pass
				2515D	Pass
C2	WBP	Cpk > 1.67, T0 samples	30 bonds from 5 pcs	2515D	Pass
C2	WBP	0 fails, post-TC, UHAST, BHAST samples	30 bonds from 4 pcs	2513D	Pass
				2514D	Pass
				2515D	Pass
C3	SD	>95% coverage, 8 hrs steam aging prior to testing	15 pcs*1 lot	2515D	Pass
C4	PD	Cpk > 1.67	10 pcs*3 lots	2513D	Pass
				2514D	Pass
				2515D	Pass

Group C-Package Assembly Integrity Tests (SOIC8-JECT-A)

Group	Item	Test Condition	QTY	Lot NO.	Result
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C1	WBS	Cpk > 1.67, T0 samples	30 bonds from 5 pcs	2515A	Pass
C1	WBS	0 fails, post-TC, UHAST, BHAST, HTS samples	30 bonds from 3 pcs Per Test Item	2513A	Pass
				2514A	Pass
				2515A	Pass
C2	WBP	Cpk > 1.67, T0 samples	30 bonds from 5 pcs	2515A	Pass
C2	WBP	0 fails, post-TC, UHAST, BHAST samples	30 bonds from 4 pcs Per Test Item	2513A	Pass
				2514A	Pass
				2515A	Pass
C3	SD	>95% coverage, 8 hrs steam aging prior to testing	15 pcs*1 lot	2515A	Pass
C4	PD	Cpk > 1.67	10 pcs*3 lots	2513A	Pass
				2514A	Pass
				2515A	Pass

Group C-Package Assembly Integrity Tests (DFN8-JECT-B)

Group	Item	Test Condition	QTY	Lot NO.	Result
C1	WBS	Cpk > 1.67, T0 samples	30 bonds from 5 pcs	2521B	Pass
C1	WBS	0 fails, post-TC, UHAST, BHAST, HTS samples	30 bonds from 3 pcs Per Test Item	2521B	Pass
				2522B	Pass
				2523B	Pass
C2	WBP	Cpk > 1.67, T0 samples	30 bonds from 5 pcs	2521B	Pass
C2	WBP	0 fails, post-TC, UHAST, BHAST samples	30 bonds from 4 pcs Per Test Item	2521B	Pass
				2522B	Pass
				2523B	Pass
C3	SD	>95% coverage, 8 hrs steam aging prior to testing	15 pcs*1 lot	2521B	Pass
C4	PD	Cpk > 1.67	10 pcs*3 lots	2521B	Pass
				2522B	Pass
				2523B	Pass

TEST GROUP D-Die Fabrication Reliability Tests

Group	Item	Test Condition	ADDITIONAL REQUIREMENTS
D1	EM	---	The Die Fabrication Reliability Tests are carried out by every fabrication site. The data, test method, calculations and internal criteria are available to the customer upon request.
D2	TDDB	---	
D3	HCI	---	

D4	NBTI	---			
D5	SM	---			
Group E-Electrical Verification Tests					
Group	Item	Test Condition	QTY	Lot NO.	Result
E1	TEST	Pre and Post Stress Electrical Test	All	All	Pass
E2	HBM	± 500V, ± 1KV, ± 2KV, ± 4KV, ± 8KV (Test @ Rm/Hot)	3 pcs*1 lot	2509A	3B
E3	CDM	± 250V, ± 500V, ± 750V, ± 2KV (Test @ Rm/Hot)	3 pcs*1 lot	2509A	C3
E4	LU	125℃, I-trigger ±200mA; 1.5 × VmaxSUP or MSV(Test @ Rm/Hot)	6pcs*1 lot	2509A	Class II A
E5	ED	CPK>1.67, test at room, hot, and cold temperature	30pcs*3lot	2513D 2514D 2515D	PASS
E9	EMC	Electromagnetic Compatibility (Radiated Emissions)	NA	NA	NA
E12	LF	SOIC8 JCET-A	Refer to JCET SOP8 Tin Whisker report		
		SOIC8 UNIMOS	Refer to UNIMOS SOP8 Tin Whisker report		
		DFN8 JCET-B	Refer to UNIMOS DFN8 Tin Whisker report		

5. MTTF&FIT

Supporting Data (Ea = 0.7 eV, Confidence Level = 60%)							MTTF (hrs)	FIT
Test Temp.	Test Voltage	Duration	QTY	Fail QTY	Operation Temp.	Operation Voltage	6.14E+07	16.27
125°C	5.5V	1000 hrs	200	0	55°C	5.5 V		
125°C	5.5V	48 hrs	2550	0	55°C	5.5 V		
125°C	5.5V	2000 hrs	200	0	55°C	5.5 V		

Note: The FIT data is generated based on Arrhenius model and voltage acceleration model.

6. Conclusion

CA-IF1044AX&1051AX-Q1 series products are qualified according to AEC-Q100&AEC-Q006 standard.

Disclaimer

This information is provided to assist customers in design and development. It could change for technology innovation without notice.

The devices are shipped after passing final test. Customers are responsible to conduct sufficient engineering and additional qualification testing to determine whether a device is suitable for use in their applications.

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Revision History

Revision	Change Log	Date
V1.0	Initial release	Oct, 2025
V1.1	Add HTOL 2000hrs result	Nov, 2025